Si Time [®]	Title:	Performance Report SiT8008B, 65MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

This report contains sample performance data for SiT8008B-65MHz.

Conditions:

- Frequency 65 MHz
- Vdd 1.8V, 2.5V, 2.8V, 3.0V, 3.3V
- Temperature 25℃
- Termination:
 - No load for IDD
 - $\circ~~50\Omega$ to GND for phase noise
 - o 15pF for other tests

Equipment:

- Agilent DSA90604 oscilloscope (6GHz, 20Gsps)
 - o Period jitter, waveform, rise/fall time, duty cycle, amplitude
- Agilent E5052B Signal Source Analyzer
 - Phase noise, integrated phase jitter
- Power supply current
 - Agilent 34401A DMM

Data:

- Random Phase jitter, Period Jitter, Duty cycle, Rise/Fall time, Amplitude, Idd
- Output waveforms
- Frequency stability versus temperature

Parameter	Units	Voltage					
	Units	1.8 V	2.5 V	2.8 V	3.0 V	3.3 V	
Random Phase jitter (900kHz - 20MHz)	ps, rms	0.62	0.66	0.69	0.67	0.68	
Random Phase jitter (12kHz - 20MHz)	ps, rms	1.43	1.43	1.47	1.47	1.47	
Period jitter	ps, rms	1.89	1.65	1.60	1.60	1.57	
Period jitter (10,000 cycles)	ps, pk-pk	14.2	11.9	11.9	11.8	11.7	
Duty cycle	%	49.9	49.8	50.2	50.6	51.1	
Rise time (20% - 80%)	ns	1.24	1.02	0.93	0.99	0.93	
Fall time (80% - 20%)	ns	1.25	0.99	0.91	0.98	0.93	
Amplitude	V	1.76	2.45	2.72	2.97	3.25	
Current consumption (no load, output enabled)	mA	4.18	4.46	4.59	4.65	4.80	
Current consumption (no load, output disabled)	mA	3.52	3.59	3.64	3.68	3.75	

Table 1. Performance data

Si Time [®]	Title:	Performance Report SiT8008B, 65MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

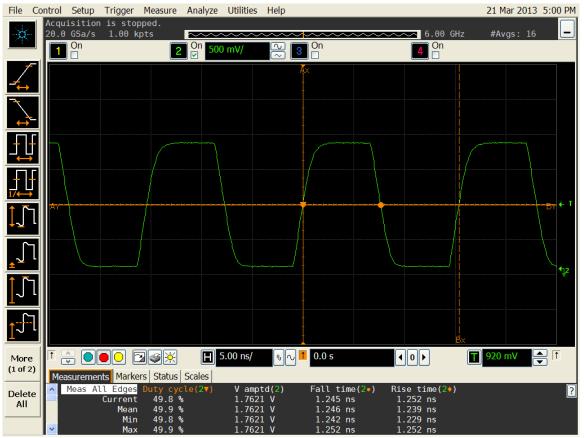


Figure 1. Duty cycle, Rise/Fall time and Amplitude 1.8V

Page 2 of 11

Si Time [®]	Title:	Performance Report SiT8008B, 65MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

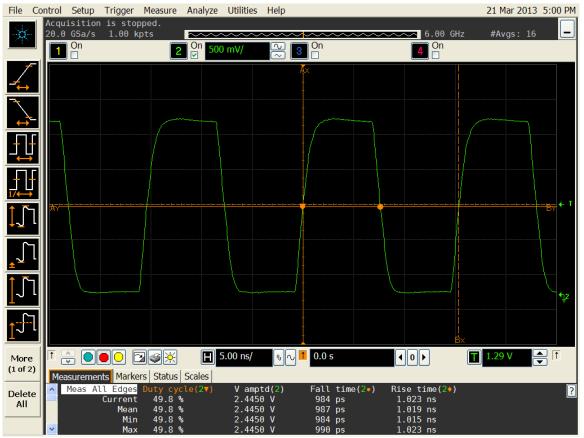


Figure 2. Duty cycle, Rise/Fall time and Amplitude 2.5V

Si Time [®]		Performance Report SiT8008B, 65MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014



Figure 3. Duty cycle, Rise/Fall time and Amplitude 2.8V

Page 4 of 11

Si Time [®]	Title:	Performance Report SiT8008B, 65MHz		
	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014



Figure 4. Duty cycle, Rise/Fall time and Amplitude 3.0V

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	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

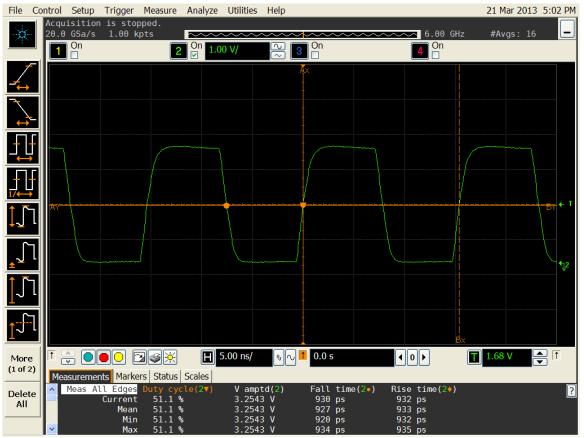


Figure 5. Duty cycle, Rise/Fall time and Amplitude 3.3V

Page 6 of 11

	Title:	Performance Report SiT8008B, 65MHz		
Si Time [®]	Туре:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

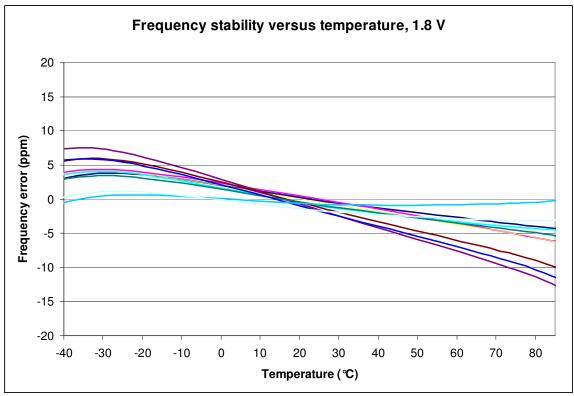


Figure 6. Frequency stability* versus temperature, 1.8 V

*Please note that frequency stability in SiTime devices is not depended on output frequency.

Si Time ^{**}	Title:	Performance Report SiT8008B, 65MHz		
	Type:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

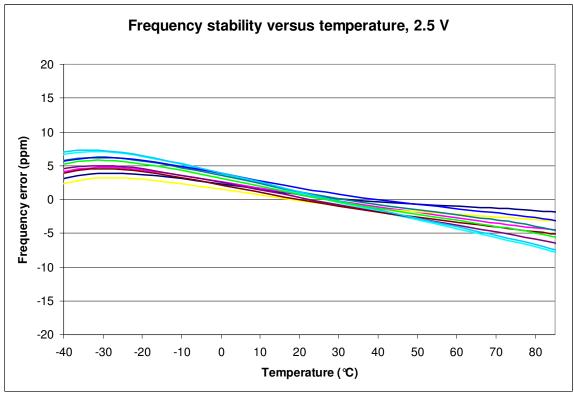


Figure 7. Frequency stability versus temperature, 2.5 V

Page 8 of 11

	Title:	Performance Report SiT8008B, 65MHz		
Si Time [®]	Type:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

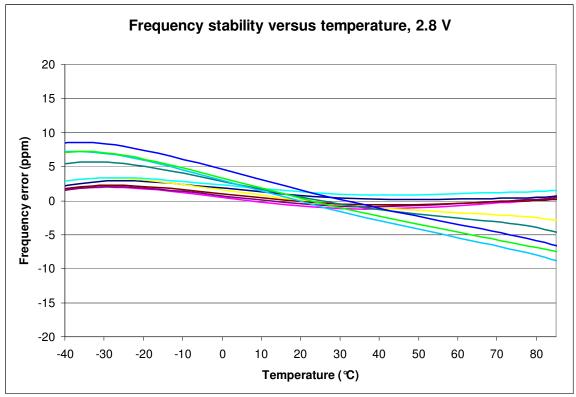


Figure 8. Frequency stability versus temperature, 2.8 V

Si Time ^{**}	Title:	Performance Report SiT8008B, 65MHz		
	Type:	Performance report	Rev:	1.0
	Orig:		Date:	Mar 31, 2014

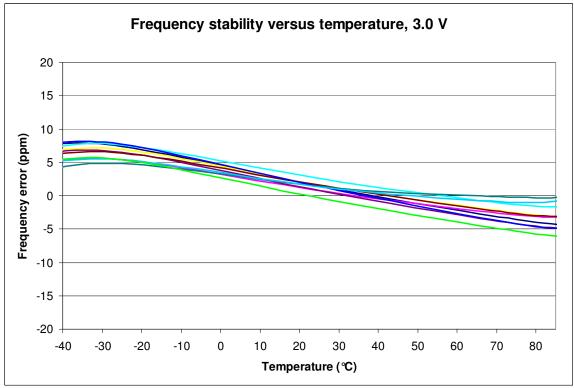


Figure 9. Frequency stability versus temperature, 3.0 V

Si Time ^{**}	Title:	Performance Report SiT8008B, 65MHz		
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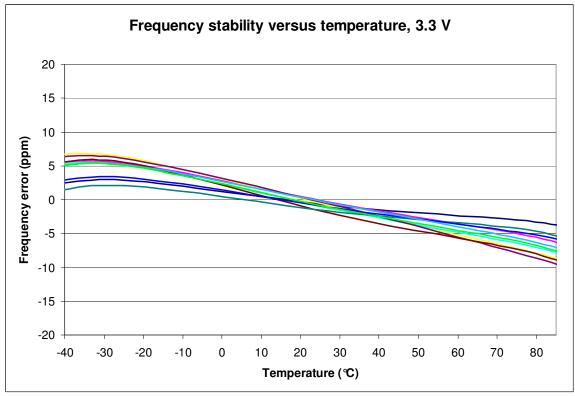


Figure 10. Frequency stability versus temperature, 3.3 V